imall

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P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)} max	Ι <u></u> Τ _A = +25°C
2014	70mΩ@ V _{GS} = -10V	-3.8A
-30V	120mΩ@ V _{GS} =-4.5V	-3.0A

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

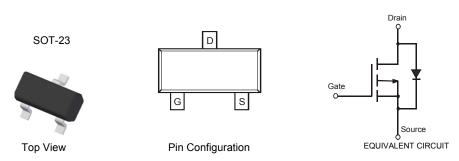
- Power management functions
- Analog Switch
- Load Switch
- **Boost Switch**

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



Ordering Information (Note 4)

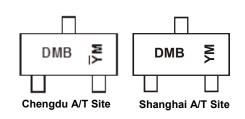
Part Number	Case	Packaging
DMP3098L-7	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead_free.html com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free,

"Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



DMB = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Notes:

Bate boat hoy												
Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris		Symbol	Value	Units	
Drain-Source Voltage		V _{DSS}	-30	V	
Gate-Source Voltage		V _{GSS}	±20	V	
Drain Current (Note 5) V _{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C		-3.8 -2.9	A
Pulsed Drain Current (Note 6)			I _{DM}	-11	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	1.08	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 5)	$R_{ heta JA}$	115	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

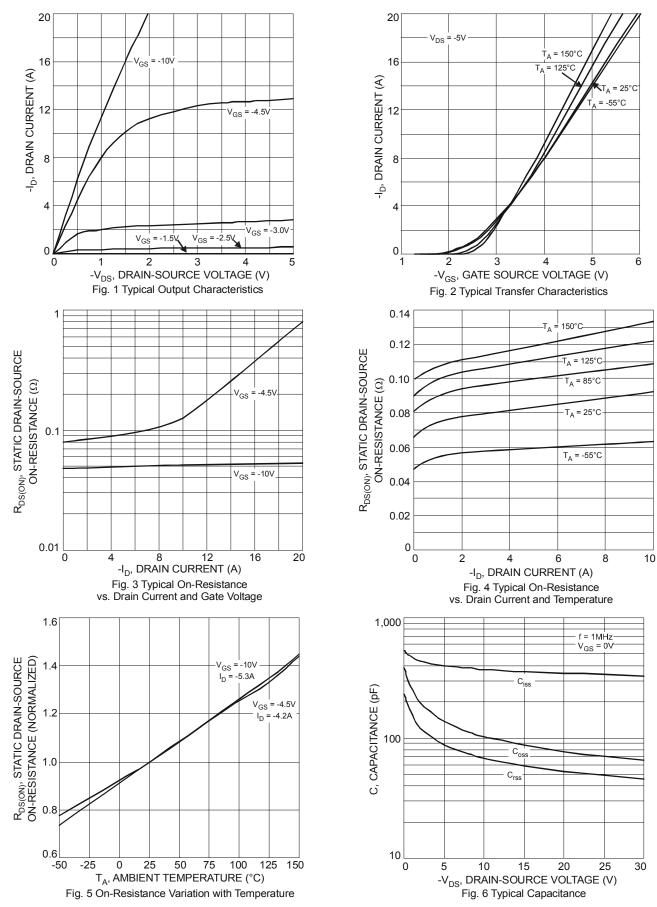
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	V _{GS} = 0V, I _D = -250µA	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-800	nA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	V _{GS} = ±20V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1.0	-1.8	-2.1	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			56	70	mΩ	V _{GS} = -10V, I _D = -3.8A	
	R _{DS} (ON)	_	98	120	11152	V _{GS} = -4.5V, I _D = -3.0A	
Forward Transfer Admittance	Y _{fs}	_	3.6	_	S	V _{DS} = -5V, I _D = -2.7A	
Diode Forward Voltage (Note 6)	V _{SD}	_	_	-1.26	V	V _{GS} = 0V, I _S = -2.7A	
DYNAMIC CHARACTERISTICS (Note 8)						•	
Input Capacitance	Ciss	_	336	1008	pF		
Output Capacitance	C _{oss}	_	70	210	pF	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	49	147	pF		
Gate Resistance	R _G	_	4.6	_	Ω	V _{GS} = 0V, V _{DS} = 0V, f = 1MHz	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Qq		4.0	8.0		V _{DS} = -15V, V _{GS} = -4.5V, I _D = -3.8A	
	Ũ		7.8	_	nC		
Gate-Source Charge	Q _{qs}	_	1.0	_		$V_{DS} = -15V, V_{GS} = -10V,$	
Gate-Drain Charge	Q _{gd}	_	2.5	_		I _D = -3.8A	
Turn-On Delay Time	t _{d(on)}	_	6.0	12.0			
Rise Time	tr	_	5.0	10.0]	V _{DS} = -15V, V _{GS} = -10V,	
Turn-Off Delay Time	t _{d(off)}		17.6	35.2	ns	$I_D = -1A, R_G = 6.0\Omega$	
Fall Time	t _f	—	9.5	19.0	1		

Notes: 5. Device mounted on FR-4 PCB on 2 oz., 0.5 in.² copper pads and t \leq 5 sec.

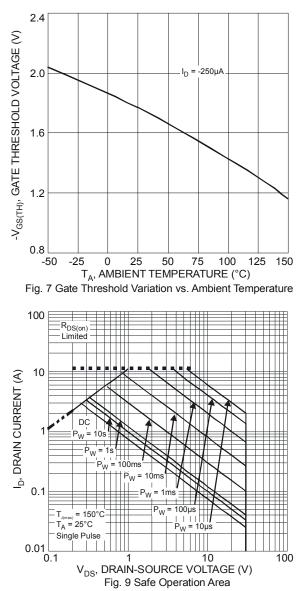
6. Pulse width ≤10μS, Duty Cycle ≤1%.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.

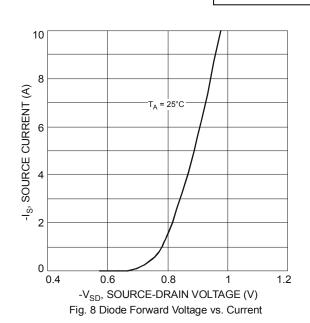


DMP3098L



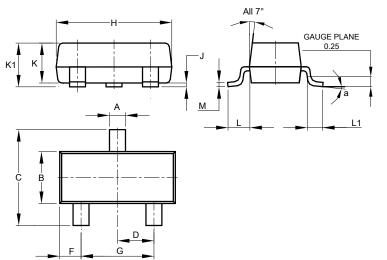






Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

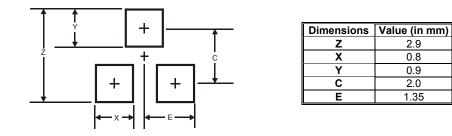


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
Κ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
Μ	0.085	0.150	0.110				
α	8°						
All Dimensions in mm							



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



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